Chapter 2 - Reading Assignments

ECE 8853 “Silicon-Based Heterostructure Devices and Circuits”
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Articles:


Reference Material:

None for this chapter

Textbook:


Chapter 2 SiGe Strained Layer Epitaxy

2.1 SiGe alloys C 2.2
2.2 stability issues C 2.7
2.3 band structure C 2.8
2.4 transport properties C 2.8

More Advanced Material (Optional):